Doc No. TT4-EA-12099

Revision. 3

Panasonic

MOS FET

MTM684100LBF

MTM684100LBF Dual P-channel MOSFET

For switching

■ Features

- Low drain-source On-state Resistance RDS(on) typ. = 32 m Ω (VGS =-4.0 V)
- Low drive voltage:1.8V drive
- Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL:Level 1 compliant)
- Marking Symbol: 10

Established: 2010-01-06

: 2013-10-15

Revised

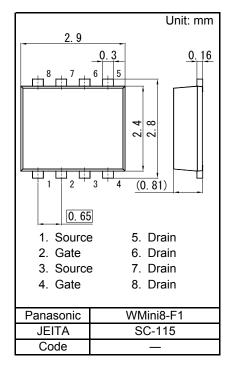
■ Basic Part Number: Dual MTM23110 (Individual)

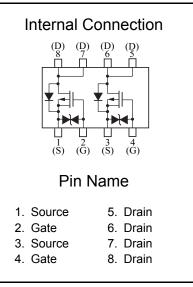
■ Packaging

Embossed type (Thermo-compression sealing): 3 000 pcs / reel (standard)

■ Absolute Maximum Ratings Ta = 25 °C Parameter Symbol Rating Unit Drain-source Voltage **VDS** -12 ٧ FET1 Gate-source Voltage VGS ٧ ±8 FET2 Drain current ID -4.8 Α -19 Peak drain current IDp Α W PD 1.0 Total power dissipation 150 °C Channel temperature Tch Overall Operating ambient temperature Topr -40 to +85 $^{\circ}$ C Storage temperature -55 to +150 Tstg

Note) *1 Glass epoxy board: 25.4 mm × 25.4 mm × 0.8 mm Copper foil of the drain portion should have a area of 300 mm² or more PD absolute maximum rating without a heat shink: 400 mW





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■ Electrical Characteristics Ta = 25°C ± 3°C

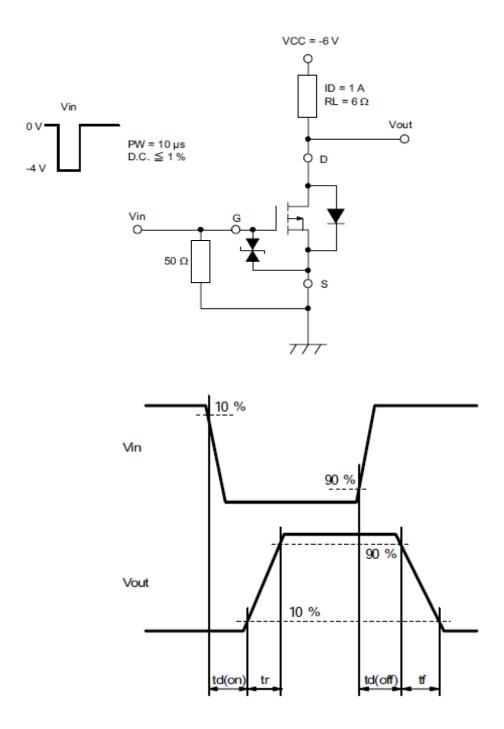
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Drain-source surrender voltage	VDSS	ID = -1 mA, VGS = 0	-12			V
Drain-source cutoff current	IDSS	VDS = -12 V, VGS = 0			-1.0	μA
Gate-source cutoff current	IGSS	$VGS = \pm 6.4 \text{ V}, VDS = 0$			±10	μA
Gate threshold voltage	Vth	ID = -1.0 mA, VDS = -6.0 V	-0.3	-0.65	-1.0	V
	RDS(ON)1	ID = -1.0 A, VGS = -4.0 V		32	42	mΩ
Drain-source ON resistance	RDS(ON)2	ID = -0.5 A, VGS = -2.5 V		37	55	mΩ
	RDS(ON)3	ID = -0.2 A, VGS = -1.8 V		50	75	mΩ
Forward transfer admittance	Yfs	ID = -1.0 A, VDS = -10 V	3.5			S
Short-circuit input capacitance (Common source)	Ciss			1200		pF
Short-circuit output capacitance (Common source)	Coss	VDS = -10 V, VGS = 0, f = 1 MHz		110		pF
Reverse transfer capacitance (Common source)	Crss			110		pF
Turn-on delay time *1	td(on)	VDD = -6 V, VGS = 0 V to -4 V		8		ns
Rise time *1	tr	ID = -1.0 A		11		ns
Turn-off delay time *1	td(off)	VDD = -6 V, VGS = -4 V to 0 V		235		ns
Fall time *1	tf	ID = -1.0 A		85		ns

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 Measuring methods for transistors.

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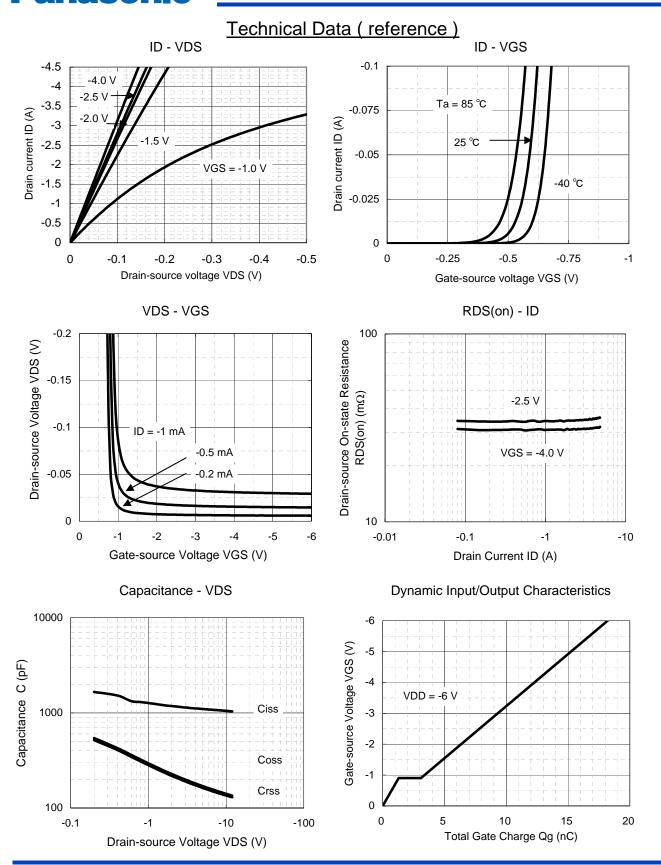
^{2. *1} Measurement circuit for Turn-on Delay Time/Rise Time/Turn-off Delay Time/Fall Time

*2 Measurement circuit for Turn-on Delay Time/Rise Time/Turn-off Delay Time/Fall Time



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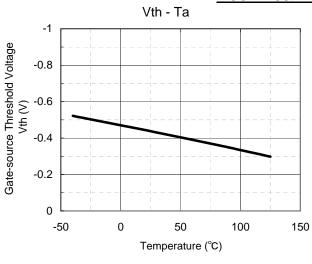


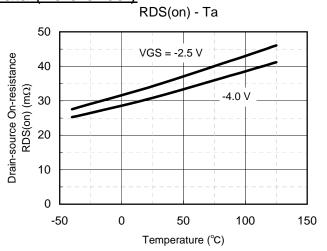
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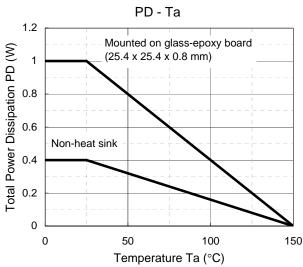
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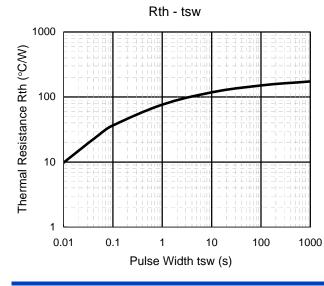
MOS FET MTM684100LBF

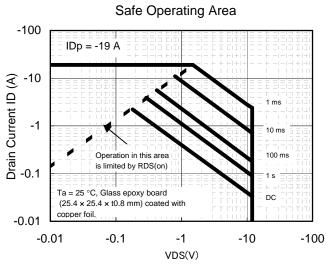
Technical Data (reference)









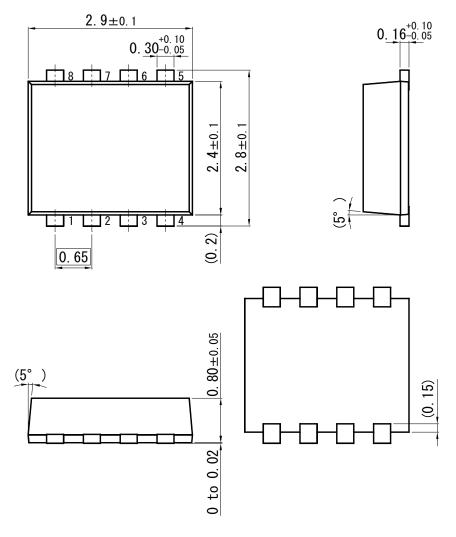


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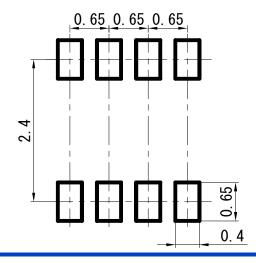
MOS FET MTM684100LBF

WMini8-F1

Unit: mm



■ Land Pattern (Reference) (Unit : mm)



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